NSN 5961-01-359-3337

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-3337 **Inclosure Material:** Metal **Overall Length:** Between 11.0 millimeters and 13.0 millimeters **Overall Width:** Between 11.0 millimeters and 13.0 millimeters **Mounting Method:** Press fit **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 400.00 milliamperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Nuclear hardness critical item **Terminal Type And Quantity:** 1 case and 1 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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